



ADVANCED TECHNICAL DATA SHEET*

DATA SHEET NO. 41014A

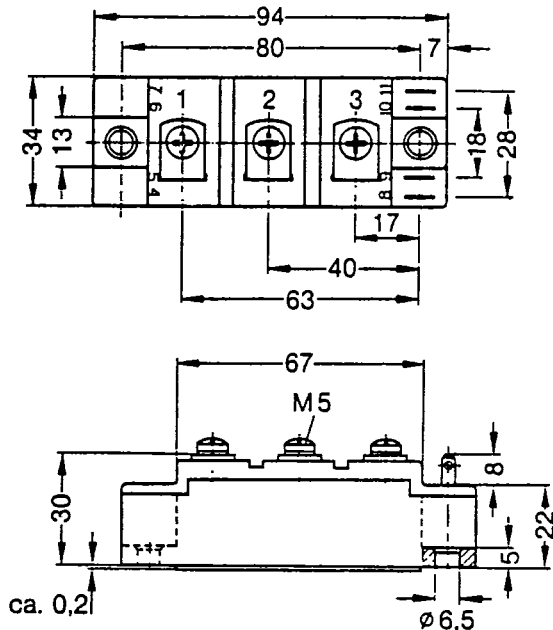
MOSBLOC™ IGBT MODULE

IXGQ50N90Y4
MAXIMUM RATINGS ($T_C = 25^\circ\text{C}$ unless otherwise indicated)

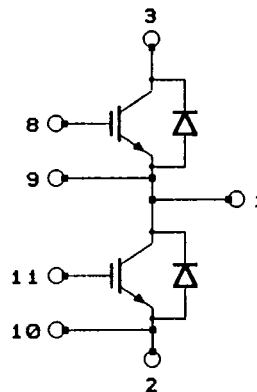
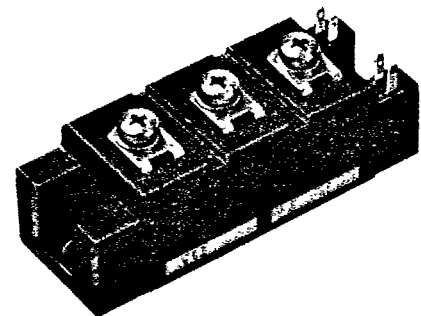
Rating	Conditions	Symbol	Value	Unit
Collector-Emitter Voltage		V_{CES}	900	V
Gate-Emitter Voltage (Continuous)		V_{GES}	± 20	V
Collector Current (IGBT)	DC, $T_C = 25^\circ\text{C}$	I_C	50	A
	DC, $T_C = 85^\circ\text{C}$	I_C	35	A
Collector Surge Current (IGBT)	1 mSec	I_{CM}	100	A
Diode Forward Current	DC	I_F	50	A
Diode Surge Current	1 mSec	I_{FM}	100	A
Maximum Junction Temperature		T_J	150	$^\circ\text{C}$
Storage Temperature		T_{stg}	-40 to +125	$^\circ\text{C}$
Thermal Resistance (IGBT)		R_{thJC}	0.5	K/W
Collector Power Dissipation		P_C	250	W
Derating (IGBT)			2.0	W/ $^\circ\text{C}$
Thermal Resistance (Diode)		R_{thJC}	0.9	K/W
Isolation Voltage	AC for 1 min.	V_{ISOL}	2500	V
Screw Torque (Mounting) (Terminals)		M_M	22	in-lb
		M_T	33	in-lb

OUTLINE DRAWING

CIRCUIT DIAGRAM



NOTE: DIMENSIONS IN mm (1 mm = 0.0394")


Y4 PACKAGE
(94mm X 34mm)

IXYS Corporation

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TEL: (408) 435-1900 • TLX: 384928 IXYS SNJ UD • FAX: (408) 435-0670

ELECTRICAL CHARACTERISTICS ($T_C=25^{\circ}\text{C}$ unless otherwise specified)

CHARACTERISTIC	TEST CONDITION		SYMBOL	MIN	TYP	MAX	UNIT
Collector-Emitter Breakdown Voltage (1)	$V_{GE} = 0\text{ V}; I_C = 1\text{ mA}$		$V_{(BR)CES}$	900			V
Collector Cut-off Current	$V_{CE} = 900\text{ V}; V_{GE} = 0\text{ V}; T_J = 25^{\circ}\text{C}$		I_{CES}			1.0	mA
	$V_{CE} = 720\text{ V}; V_{GE} = 0\text{ V}; T_J = 125^{\circ}\text{C}$		I_{CES}			15	mA
Gate Threshold Voltage	$I_C = 0.25\text{ mA}; V_{CE} = V_{GE}$		$V_{GE(th)}$	2.5		5.0	V
Gate-Emitter Leakage Current (4)	$V_{GE} = \pm 20\text{ V}; V_{CE} = 0$		I_{GES}			500	nA
Collector-Emitter Saturation Voltage	$I_C = 50\text{ A}$ $V_{GE} = 15\text{ V}$	$T_C = 25^{\circ}\text{C}$	$V_{CE(sat)}$		3.5	4.5	V
		$T_C = 125^{\circ}\text{C}$	$V_{CE(sat)}$		4.0	5.0	V
Input Capacitance	$V_{CE} = 10\text{ V}$		C_{ies}		4.5		nF
Reverse Transfer Capacitance	$V_{GE} = 0\text{ V}$ $f = 1.0\text{ MHz}$		C_{res}		100		pF
Fall Time	LOAD = INDUCTIVE $I_C = 50\text{ A}$ $V_{CC} = 600\text{ V}$ $R_G = 100\ \Omega$	$T_J = 25^{\circ}\text{C}$	t_f		200		nS
Rise Time			t_r		200		nS
Turn-off Delay			$t_{d(off)}$		1000		nS
Turn-off Energy		$T_J = 125^{\circ}\text{C}$	E_{off}		5.5		mJ

DIODE CHARACTERISTICS

CHARACTERISTIC	TEST CONDITION		SYMBOL	MIN	TYP	MAX	UNIT
Repetitive Reverse Voltage (3)			V _{RRM}			900	V
Forward Voltage (2)	I _F = 50 A; V _{GE} = 0 V		V _F			3.0	V
Reverse Recovery Time	I _F = 50 A di/dt = 100 A/μS V _{GE} = -10 V V _{RR} = 350 V	T _J = 25 °C	t _{rr}		60		nS
		T _J = 125 °C	t _{rr}		100		nS
Reverse Recovery Charge		T _J = 25 °C	q _{rr}		150		nC
		T _J = 125 °C	q _{rr}		450		nC

NOTES:

- $T_J = 25^{\circ}\text{C}$ to 150°C
- Pulse test: Pulse width $\leq 300\mu\text{S}$, duty cycle $\leq 2\%$
- Repetitive rating: Pulse width limited by maximum junction temperature.
- Gate-Emitter Voltage Transient (V_{GE}) = $\pm 30\text{ V}$.

*The data supplied herein reflects the Design Technical Objective Specification. The subject products are in Product Development. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

IXYS Corporation

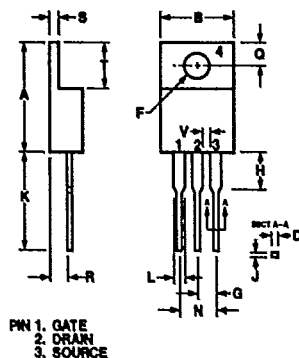
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DETAILED PACKAGE OUTLINES

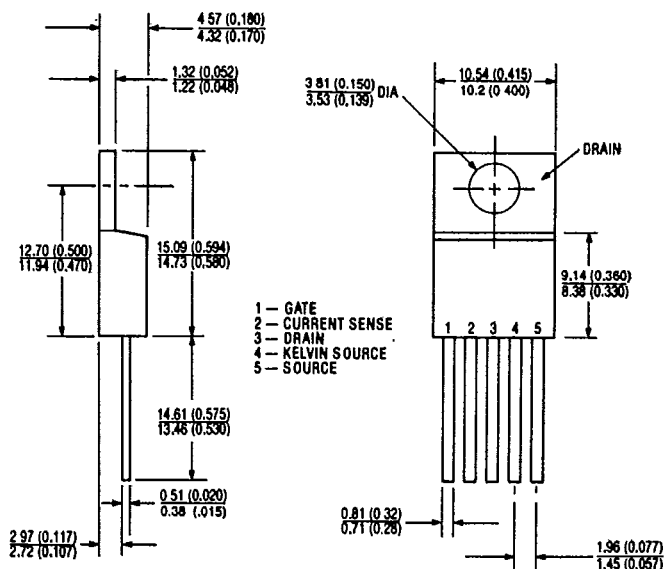
T-91-20

TO-220 AB

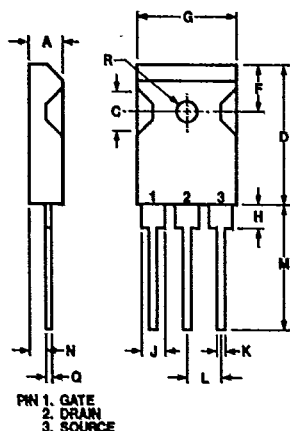


Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	14.23	16.51	.560	.650
B	9.66	10.66	.380	.420
C	3.56	4.82	.140	.190
D	0.64	0.89	.025	.035
F	3.54	4.08	.139	.161
G	2.29	2.79	.090	.110
H	—	6.35	—	.250
J	0.51	.76	.020	.030
K	12.70	14.73	.500	.580
L	1.15	1.77	.045	.070
N	4.83	5.33	.190	.210
Q	2.54	3.42	.100	.135
R	2.04	2.49	.080	.115
S	0.64	1.39	.025	.055
T	5.85	6.85	.230	.270
V	1.15	—	.045	—

CONFORMS TO OUTLINE TO-220 (IR H-7)
Dimensions in Millimeters (Inches)

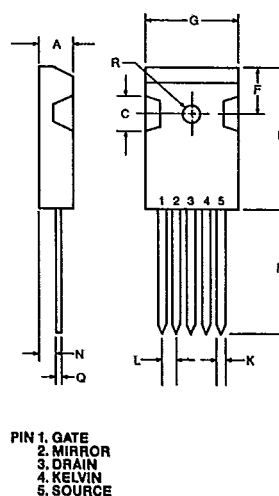


TO-247 (3 LEADED)



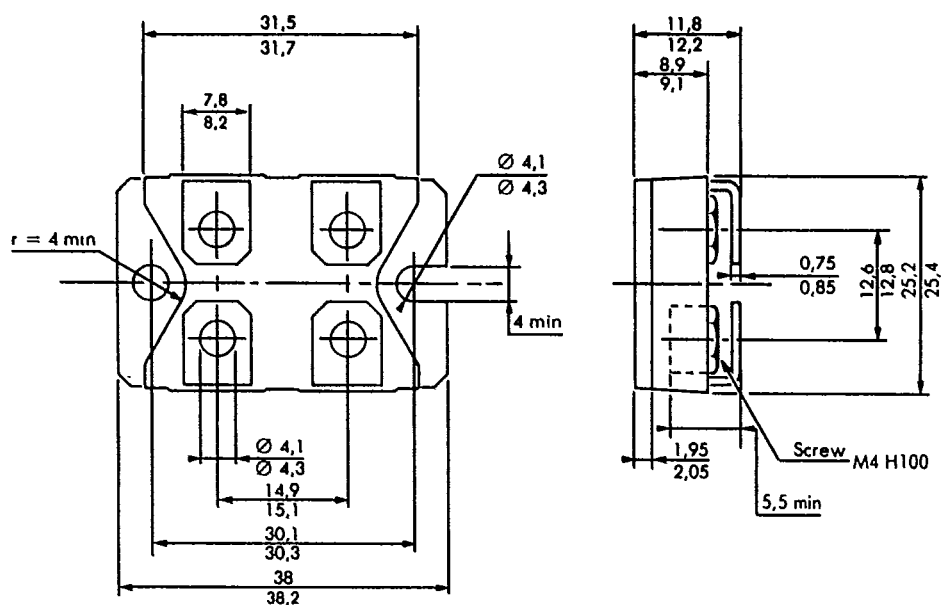
Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.7	5.3	.185	.209
C	4.5	6.0	.178	.236
D	19.7	21.4	.776	.843
F	5.3	6.1	.209	.240
G	15.3	15.9	.602	.625
H	3.7	4.3	.146	.169
J	1.95	2.4	.077	.094
J ₁	2.97	3.4	.117	.134
K	1.0	1.4	.040	.055
L	5.4	5.5	.213	.217
M	19.9	20.2	.783	.795
N	2.2	2.6	.087	.102
Q	0.4	0.8	.016	.031
R	2.9	3.3	.114	.129

TO-247 (5 LEADED)

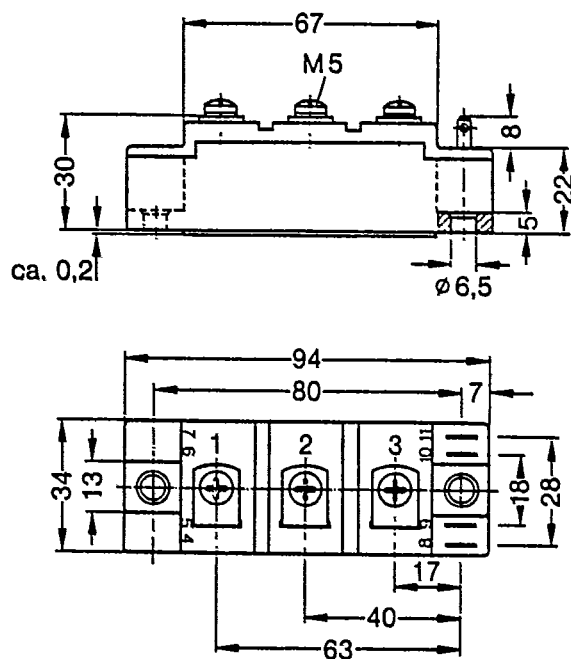


Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.7	5.3	.185	.209
C	4.5	6.0	.178	.236
D	19.7	21.4	.776	.843
F	5.3	6.1	.209	.240
G	15.3	15.9	.602	.625
K	1.1	1.3	.043	.051
L	2.51	2.56	.099	.101
M	19.9	20.2	.783	.795
N	2.2	2.6	.087	.102
Q	0.4	0.8	.016	.031
R	2.9	3.3	.114	.129

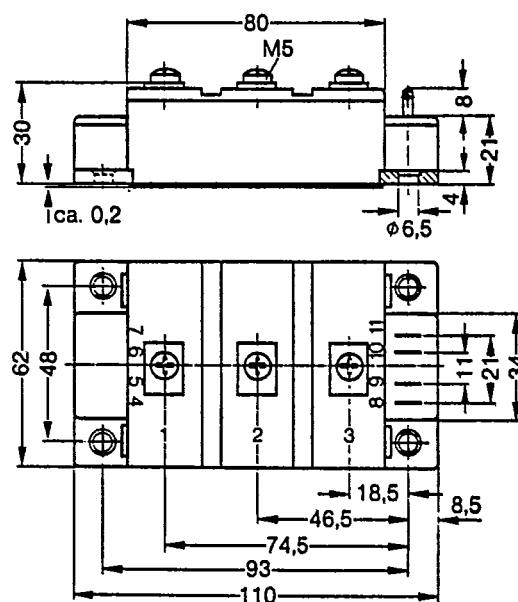
TO-238
Dimensions in Millimeters



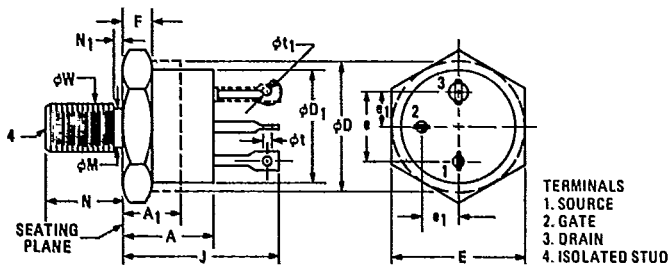
Y-4
Dimensions in Millimeters



Y-3
Dimensions in Millimeters



CONFORMS TO JEDEC OUTLINE TO-210AC (TO-61) Dimensions in Millimeters (Inches)



TERMINALS
1. SOURCE
2. GATE
3. DRAIN
4. ISOLATED STUD

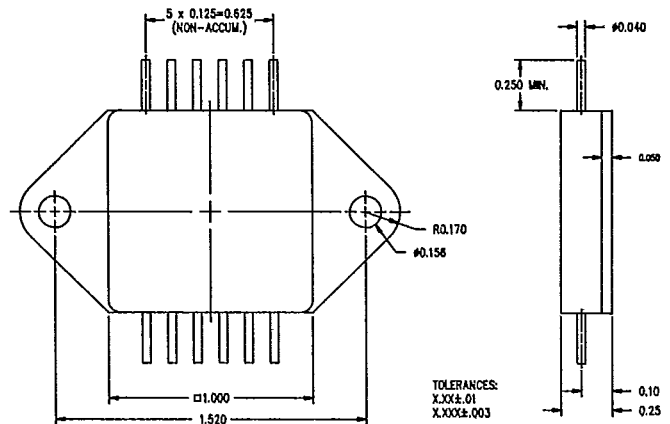
Symbol	Inches		Millimeters		Notes
	Min.	Max.	Min.	Max.	
A	0.325	0.450	8.26	11.68	
A ₁		0.270		6.86	2
ϕD	0.610	0.687	15.49	17.45	2
ϕD ₁	0.570	0.610	14.48	15.49	
E	0.667	0.687	16.94	17.45	
e	0.340	0.415	8.64	10.54	5
e ₁	0.170	0.213	4.32	5.41	5
F	0.090	0.150	2.29	3.81	1

Symbol	Inches		Millimeters		Notes
	Min.	Max.	Min.	Max.	
J	0.640	0.875	16.26	22.23	
ϕM	0.220	0.249	5.59	6.32	
N	0.422	0.455	10.72	11.56	
N ₁		0.090		2.29	
ϕt	0.055	0.072	1.19	1.83	
ϕt ₁	0.045	0.077	1.17	1.96	4
ϕW	0.2225	0.2268	5.661	5.761	3

NOTES

1. DIMENSION DOES NOT INCLUDE SEALING FLANGES.
2. PACKAGE CONTOUR OPTIONAL WITHIN DIMENSIONS SPECIFIED.
3. PITCH DIAMETER - THREAD 1/4 28 UNF 2A (COATED).
REFERENCE ISCREW THREAD STANDARDS FOR FEDERAL SERVICES - HANDBOOK H 281.
4. THIS TERMINAL CAN BE FLATTENED AND PIERCED OR HOOK TYPE.
5. POSITION OF LEADS IN RELATION TO THE HEXAGON IS NOT CONTROLLED.

QUADPAC



Z-Pac

